Lattice Semiconductor Corporation - LC5512MB-75FN256C Datasheet

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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	2.3V ~ 2.7V
Number of Logic Elements/Blocks	16
Number of Macrocells	512
Number of Gates	-
Number of I/O	193
Operating Temperature	0°C ~ 90°C (TJ)
Mounting Type	Surface Mount
Package / Case	256-BGA
Supplier Device Package	256-FPBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc5512mb-75fn256c

5000MX. Incoming signals may connect to the global routing pool or the registers in the MFBs. An Output Sharing Array (OSA) increases the number of I/O available to each MFB, allowing a complete function high-performance access to the I/O. There are four clock pins that drive four global clock nets within the device. Two sysCLOCK PLLs are provided to allow the synthesis of new clocks and control of clock skews.

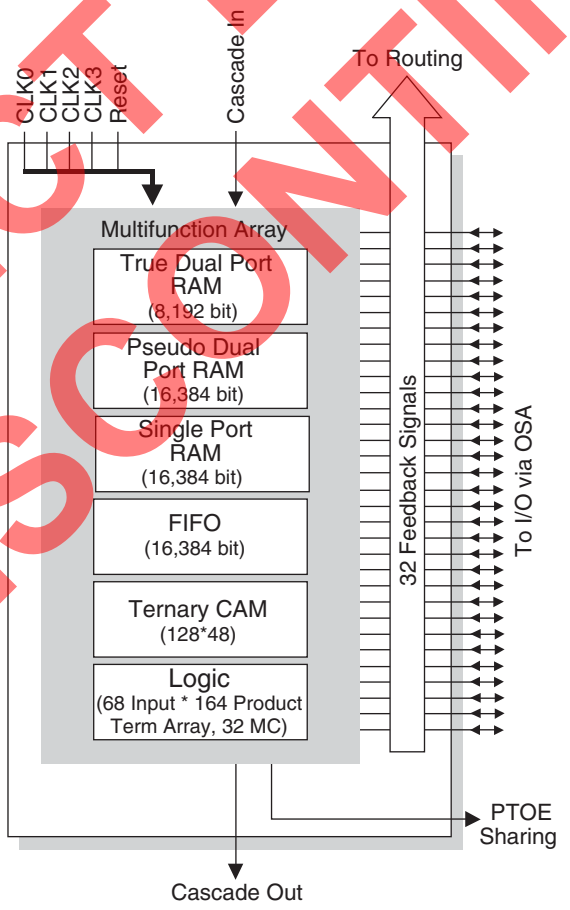
Multi-Function Block (MFB)

Each MFB in the ispXPLD 5000MX architecture can be configured in one of the six following modes. This provides a flexible approach to implementing logic and memory that allows the designer to achieve the mix of functions that are required for a particular design, maximizing resource utilization. The six modes supported by the MFB are:

- SuperWIDE Logic Mode
- True Dual-port SRAM Mode
- Pseudo Dual-port SRAM Mode
- Single-port SRAM Mode
- FIFO Mode
- Ternary CAM Mode

The MFB consists of a multi-function array and associated routing. Depending on the chosen functions the multi-function array uses up to 68 inputs from the GRP and the four global clock and reset signals. The array outputs data along with certain control functions to the macrocells. Output signals can be routed internally for use elsewhere in the device and to the sysIO banks for output. Figure 2 shows the block diagram of the MFB. The various configurations are described in more detail in the following sections.

Figure 2. MFB Block Diagram



True Dual-Port SRAM Mode

In Dual-Port SRAM Mode the multi-function array is configured as a dual port SRAM. In this mode two independent read/write ports access the same 8,192-bits of memory. Data widths of 1, 2, 4, 8, and 16 are supported by the MFB. Figure 9 shows the block diagram of the dual port SRAM.

Write data, address, chip select and read/write signals are always synchronous (registered.) The output data signals can be synchronous or asynchronous. Resets are asynchronous. All inputs on the same port share the same clock, clock enable, and reset selections. All outputs on the same port share the same clock, clock enable, and reset selections. Selections may be made independently between both inputs and outputs and ports. Table 5 shows the possible sources for the clock, clock enable and initialization signals for the various registers.

Figure 9. Dual-Port SRAM Block Diagram

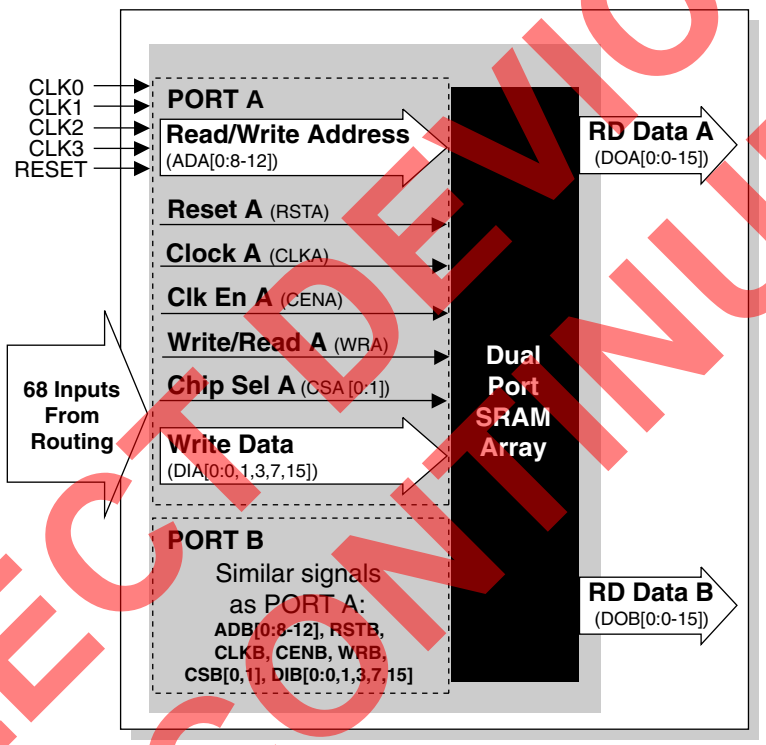


Table 5. Register Clock, Clock Enable, and Reset in Dual-Port SRAM Mode

Register	Input	Source
Address, Write Data, Read Data, Read/ Write, and Chip Select	Clock	CLKA (CLKB) or one of the global clocks (CLK0 - CLK3). The selected signal can be inverted if desired.
	Clock Enable	CENA (CENB) or one of the global clocks (CLK1 - CLK 2). The selected signal can be inverted if required.
	Reset	Created by the logical OR of the global reset signal and RSTA (RSTB). RSTA (RSTB) can be inverted is desired.

Figure 17. I/O Cell

Table 10. Shared PTOE Segments

Device	MFBs Associated With Segments
ispXPLD 5256MX	(A, B, C, D) (E, F, G, H)
ispXPLD 5512MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P)
ispXPLD 5768MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P) (Q, R, S, T) (U, V, W, Z)
ispXPLD 51024MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P) (Q, R, S, T) (U, V, W, Z) (Y, Z, AA, AB) (AC, AD, AE, AF)

sysIO Standards

Each I/O within a bank is individually configurable based on the V_{CCO} and V_{REF} settings. Some standards also require the use of an external termination voltage. Table 12 lists the sysIO standards with the typical values for V_{CCO}, V_{REF} and V_{TT}. For more information on the sysIO capability, refer to TN1000, sysIO Usage Guidelines for Lattice Devices.

Table 11. Number of I/Os per Bank

Device	Maximum Number of I/Os per Bank (n)
ispXPLD 5256MX	36
ispXPLD 5512MX	68
ispXPLD 5768MX	96
ispXPLD 51024MX	96

Absolute Maximum Ratings[1, 2, 3]

	ispXPLD 5000MC 1.8V	ispXPLD 5000MB/V 2.5V/3.3V
Supply Voltage (V_{CC})	-0.5 to 2.5V	-0.5 to 5.5V
PLL Supply Voltage (V_{CCP})	-0.5 to 2.5V	-0.5 to 5.5V
Output Supply Voltage (V_{CCO})	-0.5 to 4.5V	-0.5 to 4.5V
IEEE 1149.1 TAP Supply Voltage (V_{CCJ})	-0.5 to 4.5V	-0.5 to 4.5V
Input Voltage Applied[4, 5]	-0.5 to 5.5V	-0.5 to 5.5V
Storage Temperature	-65 to 150°C	-65 to 150°C
Junction Temperature (T_J) with Power Applied	-55 to 150°C	-55 to 150°C

1. Stress above those listed under the “Absolute Maximum Ratings” may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied (while programming, following the programming specifications).
2. Compliance with the Lattice Thermal Management document is required.
3. All voltages referenced to GND.
4. Overshoot and Undershoot of -2V to (V_{IHMAX} +2) volts not to exceed 6V is permitted for a duration of <20ns.
5. A maximum of 64 I/Os per device with V_{IN} > 3.6V is allowed.

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Units
V_{CC}	Supply Voltage for 1.8V Devices (ispXPLD 5000MC)	1.65	1.95	V
	Supply Voltage for 2.5V Devices (ispXPLD 5000MB)	2.3	2.7	V
	Supply Voltage for 3.3V Devices (ispXPLD 5000MV)	3	3.6	V
V_{CCP}	PLL Block Supply Voltage for PLL 1.8V Devices	1.65	1.95	V
	PLL Block Supply Voltage for PLL 2.5V Devices	2.3	2.7	V
	PLL Block Supply Voltage for PLL 3.3V Devices	3	3.6	V
T_J	Junction Temperature (Commercial Operation)	0	90	C
	Junction Temperature (Industrial Operation)	-40	105	C

E²CMOS Erase Reprogram Specifications

Parameter	Min.	Max.	Units
Erase/Reprogram Cycle[1]	1,000	—	Cycles

1. Valid over commercial temperature range.

Hot Socketing Characteristics[1, 2, 3, 4]

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{DK}	Input or I/O Leakage Current	0 ð V_{IN} ð 3.0V	—	+/-50	+/-800	µA

1. Insensitive to sequence of V_{CC} and V_{CCO} when V_{CCO}þð 1.0V. For V_{CCO} > 1.0V, V_{CC} min must be present. However, assumes monotonic rise/fall rates for V_{CC} and $V_{CCO,}$ provided (V_{IN} - V_{CCO})þð 3.6V.
2. 0 ð V_{CC} ð V_{CC} (MAX), 0 ð V_{CCO} ð V_{CCO} (MAX)
3. I_{DK} is additive to I_{PU}, I_{PD} or I_{BH}. Device defaults to pull-up until non-volatile cells are active.
4. LVTTL, LVCMOS only.

sysIO Differential DC Electrical Characteristics

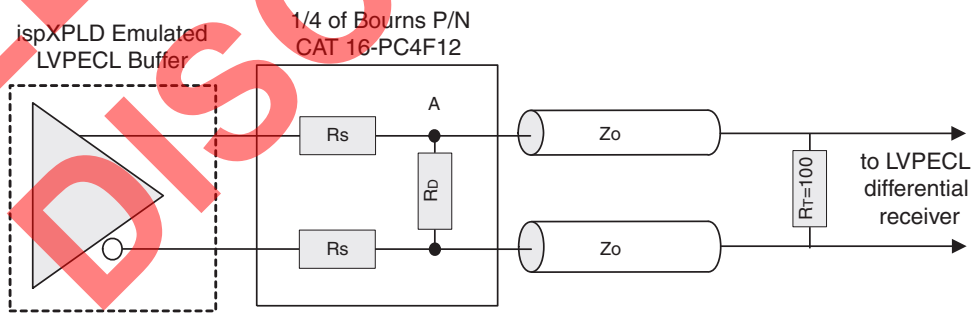
Over Recommended Operating Conditions

Parameter	Description	Test Conditions	Min.	Typ.	Max.
LVDS					
V_{INP}	Input Voltage		0V	—	2.4V
V_{THD}	Differential Input Threshold	0.2 ð V_{CM} ð 1.8V	+/-100mV	—	—
I_{IN}	Input Current	Power On	—	—	+/-10uA
V_{OH}	Output High Voltage for V_{OP} or V_{OM}	RT = 100 Ohm	—	1.38V	1.60V
V_{OL}	Output Low Voltage for V_{OP} or V_{OM}	RT = 100 Ohm	0.9V	1.03V	—
V_{OD}	Output Voltage Differential	(V_{OP} - V_{OM}), R_T = 100 Ohm	250mV	350mV	450mV
ΔV_{OD}	Change in V_{OD} Between High and Low		—	—	50mV
V_{OS}	Output Voltage Offset	(V_{OP} - V_{OM})/2, R_T = 100 Ohm	1.125V	1.20V	1.375V
ΔV_{OS}	Change in V_{OS} Between H and L		—	—	50mV
I_{OSD}	Output Short Circuit Current	V_{OD} = 0V Driver outputs shorted	—	—	24mA

LVPECL[1]								
DC Parameter	**Parameter Description**	**Min.**	**Max.**	**Min.**	**Max.**	**Min.**	**Max.**	**Units**
V_{CCO}		**3.0**		**3.3**		**3.6**		**V**
V_{IH}	Input Voltage High	1.49	2.72	1.49	2.72	1.49	2.72	V
V_{IL}	Input Voltage Low	0.86	2.125	0.86	2.125	0.86	2.125	V
V_{OH}	Output Voltage High	1.7	2.11	1.92	2.28	2.03	2.41	V
V_{OL}	Output Voltage Low	0.96	1.27	1.06	1.43	1.3	1.57	V
V_{DIFF}[2]	Differential Input voltage	0.3	—	0.3	—	0.3	—	V

1. These values are valid at the output of the source termination pack as shown above with 100-ohm differential load only (see Figure 19). The V_{OH} levels are 200mV below the standard LVPECL levels and are compatible with devices tolerant of the lower common mode ranges.
2. Valid for 0.2 ð V_{CM} ð 1.8V

Figure 19. LVPECL Driver with Three Resistor Pack



ispXPLD 5000MX Family Internal Switching Characteristics (Continued)

Over Recommended Operating Conditions

Parameter	Description	Base Parameter	-4		-45		-5		-52		-75		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
$t_{CAMWMSKS}$	Write Mask Register Setup Time before Clock	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
$t_{CAMWMSKH}$	Write Mask Register Setup Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMRSTO}$	Reset to CAM Output Delay	—	—	3.30	—	3.30	—	4.13	—	4.13	—	4.29	ns
$t_{CAMRSTR}$	Reset Recovery Time	—	1.20	—	1.20	—	1.50	—	1.50	—	1.56	—	ns
$t_{CAMRSTPW}$	Reset Pulse Width	—	0.14	—	0.14	—	0.18	—	0.18	—	0.19	—	ns
CAM – Compare Mode													
$t_{CAMDATAS}$	Data Setup Time before Clock	—	-0.41	—	-0.41	—	-0.33	—	-0.33	—	-0.31	—	ns
$t_{CAMDATAH}$	Data Hold Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMENMSKS}$	Enable Mask Register Setup Time before Clock	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
$t_{CAMENMSKH}$	Enable Mask Register Setup Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMCASC}$	CAM Width Expansion Delay	—	—	0.40	—	0.40	—	0.50	—	0.50	—	0.51	ns
t_{CAMCO}	Clock to Output (Address Out) Delay	—	—	6.19	—	6.13	—	6.81	—	6.61	—	9.63	ns
$t_{CAMMATCH}$	Clock to Match Flag Delay	—	—	6.19	—	6.13	—	6.07	—	6.61	—	10.22	ns
$t_{CAMMMATCH}$	Clock to Multi-Match Flag Delay	—	—	5.50	—	5.50	—	6.38	—	6.38	—	7.72	ns
$t_{CAMRSTFLAG}$	CAM Reset to Flags Delay	—	—	3.16	—	3.16	—	3.95	—	3.95	—	4.11	ns
Single Port RAM													
$t_{SPADDDATA}$	Address to Data Delay	—	—	5.97	—	5.97	—	5.97	—	5.97	—	7.76	ns
t_{SPMSS}	Memory Select Setup Before Clock Time	—	-0.27	—	-0.27	—	-0.27	—	-0.27	—	-0.21	—	ns
t_{SPMSH}	Memory Select Hold time after Clock Time	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
t_{SPCES}	Clock Enable Setup before Clock Time	—	2.30	—	2.30	—	2.30	—	2.30	—	9.80	—	ns
t_{SPCEH}	Clock Enable Hold time after Clock Time	—	-2.95	—	-2.95	—	-2.95	—	-2.95	—	-2.27	—	ns
t_{SPADDS}	Address Setup before Clock Time	—	-0.27	—	-0.27	—	-0.27	—	-0.27	—	-0.21	—	ns

ispXPLD 5000MX Family Timing Adders (Continued)

Parameter	Description	Base Param.	-4		-45		-5		-52		-75		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
LVCMOS_18_8mA_out	Using 1.8V CMOS Standard, 8mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.0	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVCMOS_18_12mA_out	Using 1.8V CMOS Standard, 12mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.0	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVCMOS_25_4mA_out	Using 2.5V CMOS Standard, 4mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	1.2	—	1.2	—	1.2	—	1.2	—	1.2	ns
LVCMOS_25_5.33mA_out	Using 2.5V CMOS Standard, 5.33 mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	1.0	—	1.0	—	1.0	—	1.0	—	1.0	ns
LVCMOS_25_8mA_out	Using 2.5V CMOS Standard, 8mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.4	—	0.4	—	0.4	—	0.4	—	0.4	ns
LVCMOS_25_12mA_out	Using 2.5V CMOS Standard, 12mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.4	—	0.4	—	0.4	—	0.4	—	0.4	ns
LVCMOS_25_16mA_out	Using 2.5V CMOS Standard, 16mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.4	—	0.4	—	0.4	—	0.4	—	0.4	ns
LVCMOS_33_4mA_out	Using 3.3V CMOS Standard, 4mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	1.2	—	1.2	—	1.2	—	1.2	—	1.2	ns
LVCMOS_33_5.33mA_out	Using 3.3V CMOS Standard, 5.33mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	1.2	—	1.2	—	1.2	—	1.2	—	1.2	ns
LVCMOS_33_8mA_out	Using 3.3V CMOS Standard, 8mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.8	—	0.8	—	0.8	—	0.8	—	0.8	ns
LVCMOS_33_12mA_out	Using 3.3V CMOS Standard, 12mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.6	—	0.6	—	0.6	—	0.6	—	0.6	ns
LVCMOS_33_16mA_out	Using 3.3V CMOS Standard, 16mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.6	—	0.6	—	0.6	—	0.6	—	0.6	ns
LVCMOS_33_20mA_out	Using 3.3V CMOS Standard, 20mA Drive	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.3	—	0.3	—	0.3	—	0.3	—	0.3	ns
AGP_1X_out	Using AGP 1x Standard	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.6	—	0.6	—	0.6	—	0.6	—	0.6	ns
CTT25_out	Using CTT 2.5V	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.3	—	0.3	—	0.3	—	0.3	—	0.3	ns
CTT33_out	Using CTT 3.3V	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.2	—	0.2	—	0.2	—	0.2	—	0.2	ns
GTL+_out	Using GTL+	t_{IOBUF}, t_{IOEN}, t_{IODIS}	—	0.5	—	0.5	—	0.5	—	0.5	—	0.5	ns

sysCLOCK PLL Timing

Over Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Units
t_{PWH}	Input clock, high time	80% to 80%	1.2	—	ns
t_{PWL}	Input clock, low time	20% to 20%	1.2	—	ns
t_R, t_F	Input Clock, rise and fall time	20% to 80%	—	3.0	ns
t_{INSTB}	Input clock stability, cycle to cycle (peak)		—	+/- 250	ps
f_{MDIVIN}	M Divider input, frequency range		10	320	MHz
$f_{MDIVOUT}$	M Divider output, frequency range		10	320	MHz
f_{NDIVIN}	N Divider input, frequency range		10	320	MHz
$f_{NDIVOUT}$	N Divider output, frequency range		10	320	MHz
f_{VDIVIN}	V Divider input, frequency range		100	400	MHz
$f_{VDIVOUT}$	V Divider output, frequency range		10	320	MHz
$t_{OUTDUTY}$	Output clock, duty cycle		40	60	%
$t_{JIT(CC)}$	Output clock, cycle to cycle jitter (peak)	Clean reference. 10 MHz < $f_{MDIVOUT}$ < 20 MHz or 100MHz < f_{VDIVIN} < 160 MHz[1]	—	+/- 250	ps
		Clean reference. 20 MHz < $f_{MDIVOUT}$ < 320 MHz and 160MHz < f_{VDIVIN} < 320 MHz[1]	—	+/- 150	ps
$T_{JIT(PERIOD)}$[2]	Output clock, period jitter (peak)	Clean reference. 10 MHz < $f_{MDIVOUT}$ < 20 MHz or 100MHz < f_{VDIVIN} < 160 MHz[1]	—	+/- 300	ps
		Clean reference. 20 MHz < $f_{MDIVOUT}$ < 320 MHz and 160MHz < f_{VDIVIN} < 320 MHz[1]	—	+/- 150	ps
$t_{CLK\_OUT\_DLY}$	Input clock to CLK_OUT delay	Internal feedback	—	3.0	ns
t_{PHASE}	Input clock to external feedback delta	External feedback	—	600	ps
t_{LOCK}	Time to acquire phase lock after input stable		—	25	us
t_{PLL_DELAY}	Delay increment (Lead/Lag)	Typical = +/- 250ps	+/- 120	+/- 550	ps
t_{RANGE}	Total output delay range (lead/lag)		+/- 0.84	+/- 3.85	ns
t_{PLL_RSTW}	Minimum reset pulse width		—	1.8	ns
t_{CLK_IN}[3]	Global clock input delay		—	1.0	ns
$t_{PLL\_SEC\_DELAY}$	Secondary PLL output delay (t_{PLL_DELAY})		—	1.5	ns

1. This condition assures that the output phase jitter will remain within specification.
2. Accumulated jitter measured over 10,000 waveform samples.
3. Internal timing for reference only.

Power Estimation Equations

ICC = ICC_DC + IMFB_CPLD + IMFB_ SRAM/PDPRAM/FIFO + IMFB_DPRAM + IMFB_CAM + IPLL_D

ICC_DC
Use the appropriate value for 5000MC (1.8V power supply) or 5000MV/B (2.5V/3.3V power supply) from the data sheet.

IMFB_CPLD
= ((**K0** * CPLD MFB inputs + **K1** * CPLD Logical Product Terms + **K2** * CPLD GRP from MFB + **K3** * CPLD GRP from IFB) * AF+ **K4**) * FREQ / 1000µA/mA

IMFB_CAM
= CAM Memory MFBs * ((FREQ * **K8**) + **K9**) (CAM operating in typical mode)

IMFB_ SRAM/PDPRAM/FIFO
= (WR_ PERCENT * (**K1** + WR_ PERCENT * 8 * **K0** + **K10** + **K11**) + RD_ PERCENT * (**K1** + 128 * RD_PERCENT * **K0** + 8 * OSW_PERCENT * **K2**)) * SRAM/PDPRAM/FIFO Memory MFBs * FREQ / 1000µA/mA

IMFB_ DPRAM
= (WR_ PERCENT * (2 * **K1** + 2 * WR_ PERCENT * 8 * **K0** + **K10** + **K11**) + RD_ PERCENT * (2 * **K1** + 2 * 128 * RD_PERCENT * **K0** + 8 * OSW_PERCENT * **K2**)) * DPRAM Memory MFBs * FREQ / 1000µA/mA

IPLL_D
= **K5** * PLL_FREQ * number of PLLs used. IPPL_D is the PLL digital component of the VCC supply current.

Analog portion of PLL supply current consumption, from PLL power pin:

IPLL_A = (**K6** * PLL_FREQ + **K7**) * number of PLLs used

Notes:

- ICC = Current consumption of VCC power supply (mA)
- ICC-DC = ICC DC component – Current consumption at 0Mhz (mA)
- IMFB_CPLD = CPLD (non-memory logic) current consumption (mA)
- IMFB_SRAM/PDPRAM/FIFO = Current consumption for SRAM, PDPRAM, and FIFO (mA)
- IMFB_DPRAM = Current consumption for DPRAM (mA)
- IMFB_CAM = Current consumption for CAM (mA)
- IPLL_D = PLL Current consumption of digital VCC power supply (mA)
- IPLL_A = PLL analog power pin current consumption (VCCP pin)

ispXPLD 5256MX Logic Signal Connections

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	256 fpBGA Ball Number
			Macrocell 1	Macrocell 2		
0	61N	H30	G17	H17	H31	B1
0	61P	H28	G16	H16	H29	C1
0	62N	H26	G15	H15	H27	D3
0	62P	H24	G14	H14	H25	C2
0	63N	H22	G13	H13	H23	E3
0	63P	H21	G12	H12	-	D2
-	-	VCC	-	-	-	VCC
0	64N	H20	G11	H11	-	E2
0	64P	H18/CLK_OUT0	G10	H10	H19	F2
0	65N	H16	G9	H9	H17	F1
0	65P	H14	G8	H8	H15	G1
-	-	GND	-	-	-	GND
0	66N	H12	G7	H7	H13	F3
-	-	VCCO0	-	-	-	VCCO0
0	66P	H10	G6	H6	H11	G5
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)
0	67N	H8	G5	H5	H9	H5
0	67P	H6/PLL_RST0	G4	H4	H7	G4
0	68N	H5	-	-	-	G3
0	68P	H4/PLL_FBK0	-	-	-	H3
0	69N	H2	-	-	H3	G2
0	69P	H0	-	-	H1	H1
-	GCLK0P	GCLK0	-	-	-	H2
-	-	VCCJ	-	-	-	See Power Supply and NC Connections Table
-	GCLK0N	GCLK1	-	-	-	J2
-	-	GND	-	-	-	GND
-	-	TDI	-	-	-	H6
-	-	TMS	-	-	-	H4
-	-	TCK	-	-	-	J6
-	-	TDO	-	-	-	K2
1	0P	A0/DATA0	A0	B0	A1	K3
1	0N	A2/DATA1	A1	B1	A3	J3
1	1P	A4/DATA2	A2	B2	-	J5
1	1N	A5/DATA3	A3	B3	-	J4
1	2P	A6/DATA4	A4	B4	A7	L2
1	2N	A8/DATA5	A5	B5	A9	M1
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)
1	3P	A10/DATA6	A6	B6	A11	K4
-	-	VCCO1	-	-	-	VCCO1
1	3N	A12/DATA7	A7	B7	A13	L3
-	-	GND	-	-	-	GND
1	4P	A14/INITB	A8	B8	A15	K5

ispXPLD 5256MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	256 fpBGA Ball Number
			Macrocell 1	Macrocell 2		
1	4N	A16/CSB	A9	B9	A17	L5
1	5P	A18/READ	A10	B10	A19	N1
1	5N	A20/CCLK	A11	B11	A21	M2
-	-	VCC	-	-	-	VCC
-	-	DONE	-	-	-	M4
1	6P	A22	A12	B12	A23	N3
1	6N	A24	A13	B13	A25	P4
1	7P	A26	A14	B14	A27	N5
1	7N	A28	A15	B15	A29	M6
-	-	PROGRAMB	-	-	-	R3
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)
-	-	VCCO1	-	-	-	VCC01
-	-	CFG0	-	-	-	L8
1	8P	B2	A16	B16	B3	T7
1	8N	B4	A17	B17	-	R7
1	9P	B5	A18	B18	-	N7
1	9N	B6	A19	B19	B7	P7
1	10P	B8	A20	B20	B9	T8
1	10N	B10	A21	B21	B11	R8
1	11P	B12	A22	B22	B13	M8
1	11N	B14	A23	B23	B15	P8
1	-	B16/VREF1	-	-	B17	L9
1	12P	B18	A24	B24	B19	N8
1	12N	B20	A25	B25	-	M9
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)
1	13P	B21	A26	B26	-	N10
-	-	VCCO1	-	-	-	VCCO1
1	13N	B22	A27	B27	B23	T9
1	14P	B24	A28	B28	B25	T10
1	14N	B26	A29	B29	B27	R9
-	-	VCC	-	-	-	VCC
1	15P	B28	A30	B30	B29	P9
1	15N	B30	A31	B31	B31	N9
2	16P	C0	C0	D0	C1	T11
2	16N	C2	C1	D1	C3	T12
2	17P	C4	C2	D2	-	P10
2	17N	C5	C3	D3	-	R10
2	18P	C6	C4	D4	C7	R11
-	-	VCCO2	-	-	-	VCCO2
2	18N	C8	C5	D5	C9	M10
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)
2	19P	C10	C6	D6	C11	M11
2	19N	C12	C7	D7	C13	T13

ispXPLD 5256MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	256 fpBGA Ball Number
			Macrocell 1	Macrocell 2		
3	51N	F2	E1	F1	F3	B8
3	51P	F0	E0	F0	F1	C8
0	52N	G30	G31	H31	G31	B7
0	52P	G28	G30	H30	G29	A7
-	-	GND	-	-	-	NC
0	53N	G26	G29	H29	G27	D7
0	53P	G24	G28	H28	G25	C7
0	54N	G22	G27	H27	G23	B6
-	-	VCCO0	-	-	-	VCCO0
0	54P	G21	G26	H26	-	E7
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)
0	55N	G20	G25	H25	-	E6
0	55P	G18	G24	H24	G19	A6
0	56N	G16/VREF0	G3	H3	G17	A5
0	56P	G14	G2	H2	G15	A4
0	57N	G12	G23	H23	G13	B5
0	57P	G10	G22	H22	G11	A3
0	58N	G8	G21	H21	G9	B4
0	58P	G6	G20	H20	G7	B3
0	59N	G5	G19	H19	-	C5
0	59P	G4	G18	H18	-	C6
0	60N	G2	G1	H1	G3	D5
0	60P	G0	G0	H0	G1	D6
-	-	VCCO0	-	-	-	VCCO0
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)

Global Clock LVDS pair options: GCLK0 and GCLK1, as well as GCLK2 and GCLK3, can be paired together to receive differential clocks; where GCLK0 and GCLK3 are the positive LVDS inputs

ispXPLD 5512MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	208 PQFP Pin Number	256 fpBGA Ball Number	484 fpBGA Ball Number
			Macrocell 1	Macrocell 2				
2	47N	G26	—	—	G27	108	N14	V19
—	—	GND (Bank 2)	—	—	—	109	GND (Bank 2)	GND (Bank 2)
2	48P	G28	F16	H16	G29	110	N16	T18
2	48N	G30	F17	H17	G31	111	M16	R17
2	49P	H0	F18	H18	H1	112	M14	U19
2	49N	H2	F19	H19	H3	113	M15	T19
2	50P	H4	E24	—	H5	—	—	V20
—	—	V_{CC}	—	—	—	114	VCC	VCC
2	50N	H6	E26	—	H7	—	NC	U20
2	51P	H8	F20	H20	H9	115	L13	W20
2	51N	H10	F21	H21	H11	116	L12	Y21
2	52P	H12	F22	H22	H13	117	L15	R18
2	52N	H14	F23	H23	H15	118	L16	R19
—	—	GND	—	—	—	119	GND	GND
2	53P	H16	F24	H24	H17	120	L14	W21
—	—	V_{CCO2}	—	—	—	121	V_{CCO2}	V_{CCO2}
2	53N	H18	F25	H25	H19	122	K15	Y22
—	—	GND (Bank 2)	—	—	—	123	GND (Bank 2)	GND (Bank 2)
2	54P	H20	F26	H26	H21	124	K14	R20
2	54N	H22	F27	H27	H23	125	K12	P20
2	55P	H24	F28	H28	H25	126	K13	T21
2	55N	H26	F29	H29	H27	127	J13	R21
2	56P	H28	F30	H30	H29	128	J14	U21
2	56N	H30	F31	H31	H31	129	J12	V21
—	—	TOE	—	—	—	130	J15	W22
—	—	RESET	—	—	—	131	J11	V22
—	—	GOE0	—	—	—	132	H11	T22
—	—	GOE1	—	—	—	133	H13	R22
—	—	GNDP	—	—	—	See Power Supply and NC Connections Table		
—	GCLK3N	GCLK2	—	—	—	135	H15	P16
—	—	V_{CCP}	—	—	—	See Power Supply and NC Connections Table		
—	GCLK3P	GCLK3	—	—	—	137	H16	N16
3	57N	I30	—	—	I31	138	H14	J22
3	57P	I28	—	—	I29	139	G16	H22
3	58N	I26	—	—	I27	140	G15	E22
3	58P	I24/PLL_FBK1	—	—	I25	141	F15	E21
3	59N	I22/PLL_RST1	I27	K27	I23	142	H12	G22
3	59P	I20	I26	K26	I21	143	G14	F21
—	—	GND (Bank 3)	—	—	—	144	GND (Bank 3)	GND (Bank 3)
3	60N	I18	I25	K25	I19	145	F16	H21
—	—	VCCO3	—	—	—	146	V_{CCO3}	V_{CCO3}
3	60P	I16	I24	K24	I17	147	E16	G21
—	—	GND	—	—	—	148	GND	GND

ispXPLD 5512MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	208 PQFP Pin Number	256 fpBGA Ball Number	484 fpBGA Ball Number
			Macrocell 1	Macrocell 2				
3	61N	I14	I23	K23	I15	149	G13	D22
3	61P	I12	I22	K22	I13	150	G12	D21
3	62N	I10	I21	K21	I11	151	F14	J20
3	62P	I8/CLK_OUT1	I20	K20	I9	152	E15	J19
3	63N	I6	K31	—	I7	—	F12	E20
—	—	V_{CC}	—	—	—	153	VCC	VCC
3	63P	I4	K30	L30	I5	—	F13	F20
3	64N	I2	K29	L28	I3	—	D16	H17
3	64P	I0	K28	L26	I1	—	D15	H18
—	—	GND (Bank 3)	—	—	—	—	GND (Bank 3)	GND (Bank 3)
3	65N	J30	K27	—	J31	—	—	J18
—	—	V_{CCO3}	—	—	—	—	V_{CCO3}	V_{CCO3}
3	65P	J28	K26	—	J29	—	—	H19
3	66N	J26	K25	—	J27	—	—	G20
3	66P	J24	K24	—	J25	—	—	G19
3	67N	J22	K23	—	J23	—	—	C22
3	67P	J20	K22	—	J21	—	—	C21
3	68N	J18	K21	—	J19	—	—	D20
3	68P	J16	K20	—	J17	—	—	C19
3	69N	J14	K19	—	J15	—	C16	F19
3	69P	J12	K18	—	J13	—	B16	E19
—	—	GND (Bank 3)	—	—	—	—	GND (Bank 3)	GND (Bank 3)
3	70N	J10	K17	—	J11	—	C15	G18
—	—	V_{CCO3}	—	—	—	—	V_{CCO3}	V_{CCO3}
3	70P	J8	K16	—	J9	—	B15	F18
3	71N	J6	K15	—	J7	—	E14	B20
3	71P	J4	K14	—	J5	—	D14	B19
3	72N	J2	K13	—	J3	—	E13	A20
3	72P	J0	K12	—	J1	—	A15	A19
3	73N	K30	I19	K19	K31	154	D12	D18
3	73P	K28	I18	K18	K29	155	B14	C18
3	74N	K26	I17	K17	K27	156	C13	G17
3	74P	K24	I16	K16	K25	157	A14	F16
3	75N	K22	I31	K31	K23	158	A13	E17
3	75P	K21	I30	K30	—	159	B13	D17
—	—	GND (Bank 3)	—	—	—	160	GND (Bank 3)	GND (Bank 3)
3	76N	K20	K11	L21	—	—	D11	B18
—	—	V_{CCO3}	—	—	—	161	V_{CCO3}	V_{CCO3}
3	76P	K18	K10	L20	K19	—	B12	A18
3	77N	K16	K9	L18	K17	—	C12	C17
3	77P	K14	K8	L16	K15	—	E11	B17
3	78N	K12	K7	L12	K13	—	—	C16
3	78P	K10	K6	L10	K11	—	—	B16

ispXPLD 5768MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Inputs	256 fpBGA Ball Number	484 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
0	143N	U22	U27	W27	U23	—	K6
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	143P	U20	U26	W26	U21	—	K3
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	144N	U18	U25	W25	U19	—	K5
0	144P	U16	U24	W24	U17	—	K2
0	145N	U14	U23	W23	U15	—	L5
0	145P	U12	U22	W22	U13	—	K1
0	146N	U10	U21	W21	U11	—	L6
0	146P	U8	U20	W20	U9	—	L1
0	147N	U6	U19	W19	U7	—	M5
0	147P	U4	U18	W18	U5	—	L2
0	148N	U2	U17	W17	U3	—	N5
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	148P	U0	U16	W16	U1	—	L3
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	149N	W30	U15	W15	W31	—	M6
0	149P	W28	U14	W14	W29	—	M2
0	150N	W26	U13	W13	W27	—	P5
-	-	VCC	-	-	-	VCC	VCC
0	150P	W24	U12	W12	W25	—	P6
0	151N	W22	U11	W11	W23	—	M3
0	151P	W20	U10	W10	W21	—	N6
0	152N	W18	U9	W9	W19	—	N2
0	152P	W16	U8	W8	W17	—	P1
-	-	GND	-	-	-	GND	GND
0	153N	W14	U7	W7	W15	—	N3
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	153P	W12	U6	W6	W13	—	M8
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	154N	W10	U5	W5	W11	—	N8
0	154P	W8	U4	W4	-	—	P2
0	155N	W6	U3	W3	W7	—	P8
0	155P	W4	U2	W2	W5	—	N4
0	156N	W2	U1	W1	W3	G2	H1
0	156P	W0	U0	W0	W1	H1	J1
-	GCLK0P	GCLK0	-	-	-	H2	N7
-	-	VCCJ	-	-	-	See Power Supply and NC Connections Table	
-	GCLK0N	GCLK1	-	-	-	J2	P7
-	-	GND	-	-	-	GND	GND
-	-	TDI	-	-	-	H6	R1
-	-	TMS	-	-	-	H4	R2

ispXPLD 5768MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Inputs	256 fpBGA Ball Number	484 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
2	29N	E2	F1	H1	E3	T12	AA12
-	-	GND	-	-	-	GND	GND
2	30P	E4	F2	H2	E5	P10	Y12
2	30N	E6	F3	H3	E7	R10	AA13
2	31P	E8	F4	H4	E9	R11	V12
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	31N	E10	F5	H5	E11	M10	U12
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	32P	E12	F6	H6	E13	M11	AB13
2	32N	E14	F7	H7	E15	T13	Y13
2	33P	E16	H0	-	E17	P11	V13
2	33N	E18/VREF2	H1	-	E19	T14	W13
2	34P	E20	F8	H8	E21	R12	V14
2	34N	E22	F9	H9	E23	R13	W14
2	35P	E24	F10	H10	E25	N11	Y14
2	35N	E26	F11	H11	E27	T15	AB14
2	36P	E28	F12	H12	E29	R14	AB15
2	36N	E30	F13	H13	E31	N12	AA15
2	37P	F0	F14	H14	F1	P12	U13
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	37N	F2	F15	H15	F3	R15	U14
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	38P	F4	H2	E0	F5	—	W15
2	38N	F6	H3	E2	F7	—	W16
2	39P	F8	H4	E4	F9	—	Y16
2	39N	F10	H5	E6	F11	—	AA16
2	40P	F12	H6	E8	F13	—	AB16
2	40N	F14	H7	E10	F15	—	AA17
2	41P	F16	H8	E12	F17	—	Y17
2	41N	F18	H9	E16	F19	—	AA18
2	42P	F20	H10	E20	F21	—	W17
-	-	VCC	-	-	-	VCC	VCC
2	42N	F22	H11	E22	F23	—	W18
-	-	GND	-	-	-	GND	GND
2	43P	F24	H12	-	F25	—	V15
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	43N	F26	H13	-	F27	—	U15
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	44P	F28	H14	-	F29	P13	Y18
2	44N	F30	H15	-	F31	P15	V17
2	45P	G0	H16	-	G1	M13	V16
2	45N	G2	H17	-	G3	P14	U16
2	46P	G4	H18	-	G5	—	AB18

ispXPLD 51024MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/Function	Alternate Outputs		Alternate Input	484 fpBGA Ball Number	672 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
-	GCLK3P	GCLK3	-	-	-	N16	N24
3	93N	R0	T31	R31	R1	J22	N23
3	93P	R2	T30	R30	R3	H22	N22
3	94N	R4	T29	R29	R5	N19	M26
3	94P	R6	T28	R28	R7	P15	M25
3	95N	R8	T27	R27	R9	P21	M23
3	95P	R10	T26	R26	R11	N15	M22
-	-	GND (Bank 3)	-	-	-	GND (Bank 3)	GND (Bank 3)
3	96N	R12	T25	R25	R13	M15	N20
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	96P	R14	T24	R24	R15	N20	M20
-	-	GND	-	-	-	GND	GND
3	97N	R16	T23	R23	R17	P22	N21
3	97P	R18	T22	R22	R19	N21	M21
3	98N	R20	T21	R21	R21	N17	M24
3	98P	R22	T20	R20	R23	M20	L24
3	99N	R24	T19	R19	R25	P17	L23
-	-	VCC	-	-	-	VCC	VCC
3	99P	R26	T18	R18	R27	P18	L22
3	100N	R28	T17	R17	R29	M21	L25
3	100P	R30	T16	R16	R31	M17	K26
-	-	GND (Bank 3)	-	-	-	GND (Bank 3)	GND (Bank 3)
3	101N	T0	T15	R15	T1	L20	K25
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	101P	T2	T14	R14	T3	N18	K24
3	102N	T4	T13	R13	T5	L21	K23
3	102P	T6	T12	R12	T7	M18	K22
3	103N	T8	T11	R11	T9	L22	J25
3	103P	T10	T10	R10	T11	L17	J24
3	104N	T12	T9	R9	T13	K22	L21
3	104P	T14	T8	R8	T15	L18	K21
3	105N	T16	T7	R7	T17	K21	L20
3	105P	T18	T6	R6	T19	K18	K20
-	-	GND (Bank 3)	-	-	-	GND (Bank 3)	GND (Bank 3)
3	106N	T20	T5	R5	T21	K20	J23
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	106P	T22	T4	R4	T23	K17	J22
3	107N	T24	T3	R3	T25	K19	J26
3	107P	T26	T2	R2	T27	J17	H26
3	108N	T28	T1	R1	T29	E22	H25
3	108P	T30/PLL_FBK1	T0	R0	T31	E21	H24
3	109N	U0/PLL_RST1	X27	V27	U1	G22	H23
3	109P	U2	X26	V26	U3	F21	H22

ispXPLD 51024MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/Function	Alternate Outputs		Alternate Input	484 fpBGA Ball Number	672 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
3	126N	W4	V11	U21	W5	B18	E19
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	126P	W6	V10	U20	W7	A18	E18
-	-	GND	-	-	-	GND	GND
3	127N	W8	V9	U18	W9	C17	C24
-	-	VCC	-	-	-	VCC	VCC
3	127P	W10	V8	U16	W11	B17	C23
3	128N	W12	V7	U12	W13	C16	D22
3	128P	W14	V6	U10	W15	B16	D21
3	129N	W16	V5	U8	W17	F13	E21
3	129P	W18	V4	U6	W19	F15	D20
3	130N	W20	V3	U5	W21	D16	D19
3	130P	W22	V2	U4	W23	E16	D18
3	131N	W24	V1	U2	W25	A16	C22
3	131P	W26	V0	U0	W27	A15	C21
-	-	GND (Bank 3)	-	-	-	GND (Bank 3)	GND (Bank 3)
3	132N	W28	X15	V15	W29	B15	C20
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	132P	W30	X14	V14	W31	A14	C19
3	133N	X0	X13	V13	X1	D15	C18
3	133P	X2	X12	V12	X3	E15	C17
3	134N	X4	X11	V11	X5	D14	B24
3	134P	X6	X10	V10	X7	F14	B23
3	135N	X8	X9	V9	X9	A13	B22
3	135P	X10	X8	V8	X11	B13	B21
3	136N	X12/VREF3	X29	V29	X13	C14	B20
3	136P	X14	X28	V28	X15	E14	B19
3	137N	X16	X7	V7	X17	E13	B18
3	137P	X18	X6	V6	X19	F12	B17
-	-	GND (Bank 3)	-	-	-	GND (Bank 3)	GND (Bank 3)
3	138N	X20	X5	V5	X21	D13	A24
-	-	VCCO3	-	-	-	VCCO3	VCCO3
3	138P	X22	X4	V4	X23	C13	A23
3	139N	X24	X3	V3	X25	E12	A22
-	-	GND	-	-	-	GND	GND
3	139P	X26	X2	V2	X27	C12	A21
-	-	VCC	-	-	-	VCC	VCC
3	140N	X28	X1	V1	X29	B12	A20
3	140P	X30	X0	V0	X31	A12	A19
0	141N	Y30	Y31	AA31	Y31	E11	A18
-	-	VCC	-	-	-	VCC	VCC
0	141P	Y28	Y30	AA30	Y29	C11	A17
-	-	GND	-	-	-	GND	GND

Global Clock LVDS pair options: GCLK0 and GCLK1, as well as GCLK2 and GCLK3, can be paired together to receive differential clocks; where GCLK0 and GCLK3 are the positive LVDS inputs.

Lead-Free Packaging

ispXPLD 5000MC (1.8V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MC	LC5256MC-4FN256C	256	1.8	4.0	Lead-free fpBGA	256	141	C
	LC5256MC-5FN256C	256	1.8	5.0	Lead-free fpBGA	256	141	C
	LC5256MC-75FN256C	256	1.8	7.5	Lead-free fpBGA	256	141	C
LC5512MC	LC5512MC-45QN208C	512	1.8	4.5	Lead-free PQFP	208	149	C
	LC5512MC-75QN208C	512	1.8	7.5	Lead-free PQFP	208	149	C
	LC5512MC-45FN256C	512	1.8	4.5	Lead-free fpBGA	256	193	C
	LC5512MC-75FN256C	512	1.8	7.5	Lead-free fpBGA	256	193	C
	LC5512MC-45FN484C	512	1.8	4.5	Lead-free fpBGA	484	253	C
	LC5512MC-75FN484C	512	1.8	7.5	Lead-free fpBGA	484	253	C
LC5768MC	LC5768MC-5FN256C	768	1.8	5.0	Lead-free fpBGA	256	193	C
	LC5768MC-75FN256C	768	1.8	7.5	Lead-free fpBGA	256	193	C
	LC5768MC-5FN484C	768	1.8	5.0	Lead-free fpBGA	484	317	C
	LC5768MC-75FN484C	768	1.8	7.5	Lead-free fpBGA	484	317	C
LC51024MC	LC51024MC-52FN484C	1024	1.8	5.2	Lead-free fpBGA	484	317	C
	LC51024MC-75FN484C	1024	1.8	7.5	Lead-free fpBGA	484	317	C
	LC51024MC-52FN672C	1024	1.8	5.2	Lead-free fpBGA	672	381	C
	LC51024MC-75FN672C	1024	1.8	7.5	Lead-free fpBGA	672	381	C

ispXPLD 5000MC (1.8V) Lead-Free Industrial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MC	LC5256MC-5FN256I	256	1.8	5.0	Lead-free fpBGA	256	141	I
	LC5256MC-75FN256I	256	1.8	7.5	Lead-free fpBGA	256	141	I
LC5512MC	LC5512MC-75QN208I	512	1.8	7.5	Lead-free PQFP	208	149	I
	LC5512MC-75FN256I	512	1.8	7.5	Lead-free fpBGA	256	193	I
	LC5512MC-75FN484I	512	1.8	7.5	Lead-free fpBGA	484	253	I
LC5768MC	LC5768MC-75FN256I	768	1.8	7.5	Lead-free fpBGA	256	193	I
	LC5768MC-75FN484I	768	1.8	7.5	Lead-free fpBGA	484	317	I
LC51024MC	LC51024MC-75FN484I	1024	1.8	7.5	Lead-free fpBGA	484	317	I
	LC51024MC-75FN672I	1024	1.8	7.5	Lead-free fpBGA	672	381	I